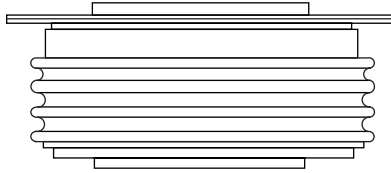


## Fast Recovery Diodes (Hockey PUK Version), 1650/1825 A



DO-200AC (K-PUK)

**FEATURES**

- High power FAST recovery diode series
- 2.0 to 3.0  $\mu$ s recovery time
- High voltage ratings up to 3000 V
- High current capability
- Optimized turn-on and turn-off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press PUK encapsulation
- Case style conform to JEDEC DO-200AC (K-PUK)
- Maximum junction temperature 150 °C
- Lead (Pb)-free


**RoHS  
COMPLIANT**
**PRODUCT SUMMARY**

$I_{F(AV)}$	1650/1825 A
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**TYPICAL APPLICATIONS**

- Snubber diode for GTO
- High voltage freewheeling diode
- Fast recovery rectifier applications

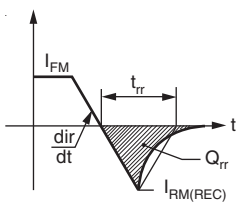
**MAJOR RATINGS AND CHARACTERISTICS**

PARAMETER	TEST CONDITIONS	SD1553C..K		UNITS
		S20	S30	
$I_{F(AV)}$		1825	1650	A
	$T_{hs}$	55	55	°C
$I_{F(RMS)}$		3100	2800	A
$I_{FSM}$	50 Hz	25 000	22 000	
	60 Hz	26 180	23 000	
$V_{RRM}$	Range	1800 to 2500	1800 to 3000	V
$t_{rr}$		2.0	3.0	$\mu$ s
	$T_J$	25		°C
$T_J$	- 40 to 150			

**ELECTRICAL SPECIFICATIONS**
**VOLTAGE RATINGS**

TYPE NUMBER	VOLTAGE CODE	$V_{RRM}$ , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA
SD1553C..S20K	18	1800	1900	75
	22	2200	2300	
	25	2500	2600	
SD1553C..S30K	18	1800	1900	
	22	2200	2300	
	25	2500	2600	
	28	2800	2900	
	30	3000	3100	

FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS	SD1553C..K		UNITS		
			S20	S30			
Maximum average forward current at heatsink temperature	$I_{F(AV)}$	180° conduction, half sine wave Double side (single side) cooled	1825 (865)	1650 (790)	A		
			55 (85)	55 (85)	°C		
Maximum RMS forward current	$I_{F(RMS)}$	25 °C heatsink temperature double side cooled	3100	2800			
Maximum peak, one-cycle forward, non-repetitive surge current	$I_{FSM}$	Sinusoidal half wave, initial $T_J = T_J$ maximum	t = 10 ms	No voltage reappplied	25 000	22 000	A
			t = 8.3 ms	No voltage reappplied	26 180	23 000	
			t = 10 ms	100 % $V_{RRM}$ reappplied	21 030	18 500	
			t = 8.3 ms	100 % $V_{RRM}$ reappplied	22 010	19 370	
Maximum $I^2t$ for fusing	$I^2t$		t = 10 ms	No voltage reappplied	3126	2421	kA <sup>2</sup> s
			t = 8.3 ms	No voltage reappplied	2854	2210	
			t = 10 ms	100 % $V_{RRM}$ reappplied	2210	1712	
			t = 8.3 ms	100 % $V_{RRM}$ reappplied	2018	1563	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied	31 260	24 210	kA <sup>2</sup> √s		
Low level value of threshold voltage	$V_{F(TO)1}$	(16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum	1.15	1.31	V		
High level value of threshold voltage	$V_{F(TO)2}$	( $I > \pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum	1.29	1.45			
Low level value of forward slope resistance	$r_{f1}$	(16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum	0.27	0.32	mΩ		
High level value of forward slope resistance	$r_{f2}$	( $I > \pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum	0.25	0.30			
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 4000$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sinusoidal wave	2.23	2.60	V		

RECOVERY CHARACTERISTICS								
CODE	MAXIMUM VALUE AT $T_J = 25$ °C	TEST CONDITIONS			TYPICAL VALUES AT $T_J = 150$ °C			
	$t_{rr}$ AT 25 % $I_{RRM}$ (μs)	$I_{pk}$ SQUARE PULSE (A)	dI/dt (A/μs)	$V_r$ (V)	$t_{rr}$ AT 25 % $I_{RRM}$ (μs)	$Q_{rr}$ (μC)	$I_{rr}$ (A)	
S20	2.0	1000	100	- 50	4.5	650	240	
S30	3.0				5.0	780	260	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	$T_J, T_{Stg}$		- 40 to 150	°C
Maximum thermal resistance, case junction to heatsink	$R_{thJ-hs}$	DC operation single side cooled	0.04	K/W
		DC operation double side cooled	0.02	
Mounting force, ± 10 %			22 250 (2250)	N (kg)
Approximate weight			425	g
Case style		See dimensions - link at the end of datasheet	DO-200AC (K-PUK)	



<b><math>\Delta R_{thJ-hs}</math> CONDUCTION</b>						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.0018	0.0019	0.0012	0.0012	T <sub>J</sub> = T <sub>J</sub> maximum	K/W
120°	0.0021	0.0021	0.0021	0.0021		
90°	0.0027	0.0027	0.0029	0.0029		
60°	0.0039	0.0039	0.0041	0.0041		
30°	0.0067	0.0067	0.0068	0.0068		

**Note**

- The table above shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC

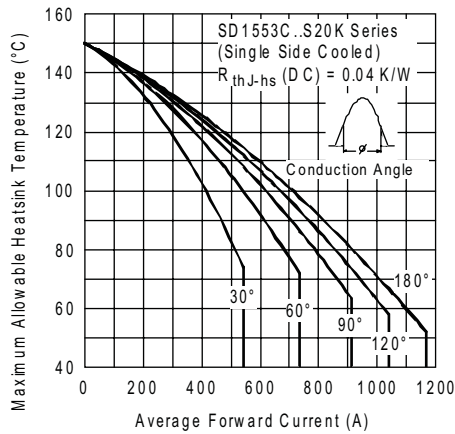


Fig. 1 - Current Ratings Characteristics

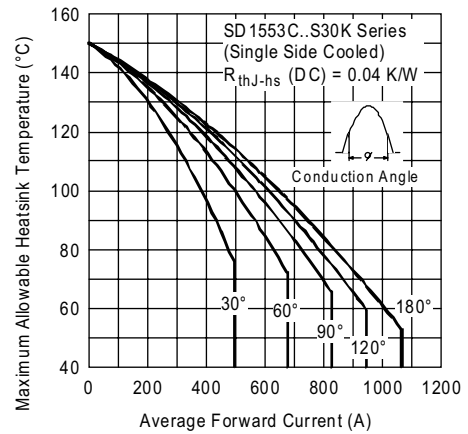


Fig. 3 - Current Ratings Characteristics

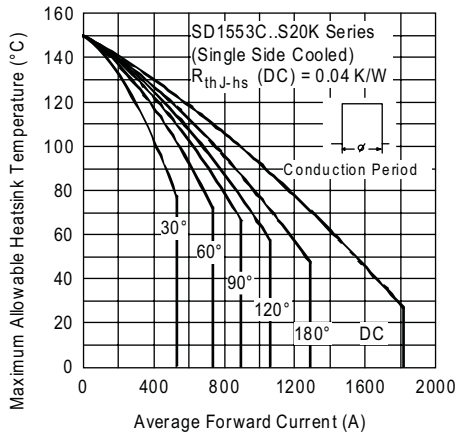


Fig. 2 - Current Ratings Characteristics

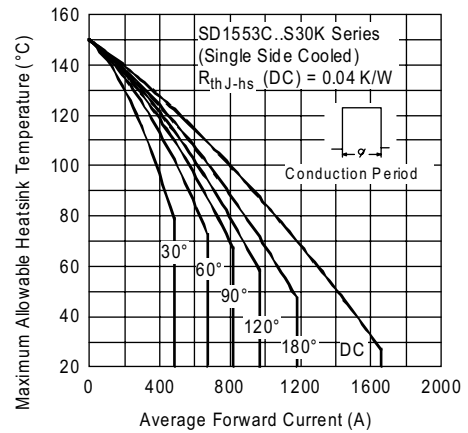


Fig. 4 - Current Ratings Characteristics

# SD1553C..K Series



Vishay High Power Products

Fast Recovery Diodes  
(Hockey PUK Version),  
1650/1825 A

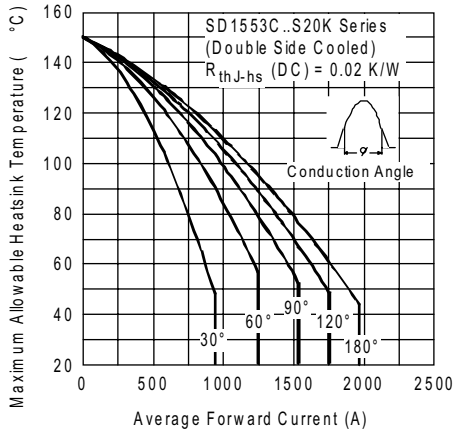


Fig. 5 - Current Ratings Characteristics

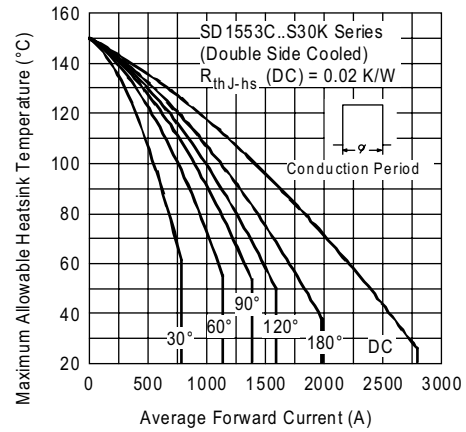


Fig. 8 - Current Ratings Characteristics

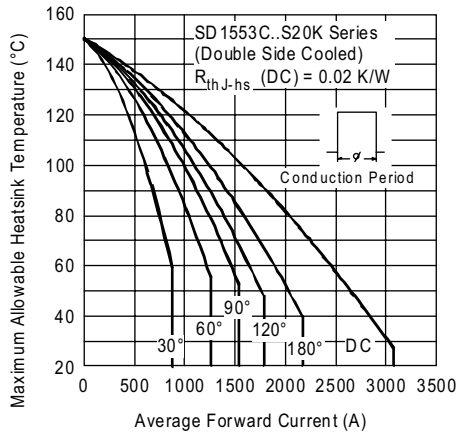


Fig. 6 - Current Ratings Characteristics

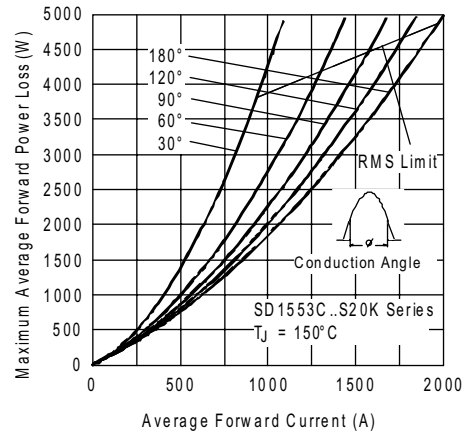


Fig. 9 - Forward Power Loss Characteristics

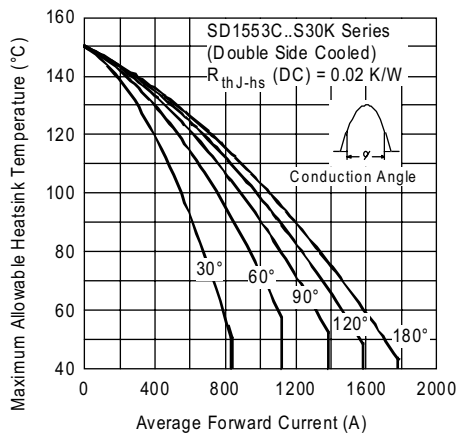


Fig. 7 - Current Ratings Characteristics

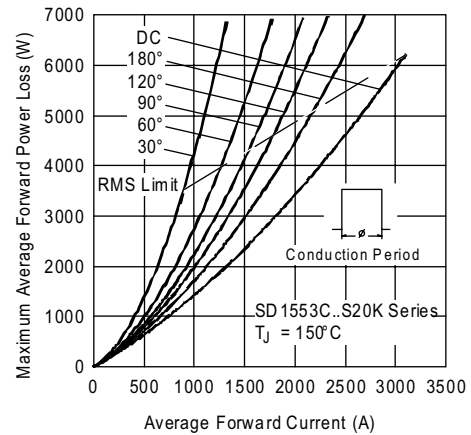


Fig. 10 - Forward Power Loss Characteristics

## Fast Recovery Diodes (Hockey PUK Version), 1650/1825 A

Vishay High Power Products

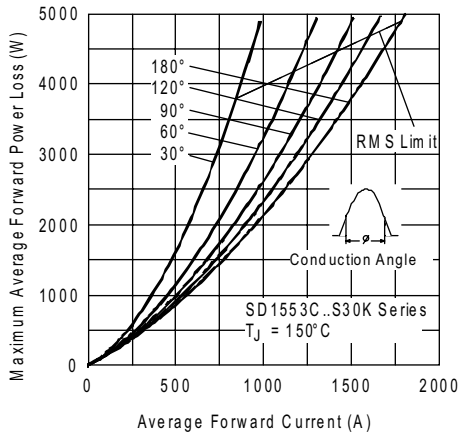


Fig. 11 - Forward Power Loss Characteristics

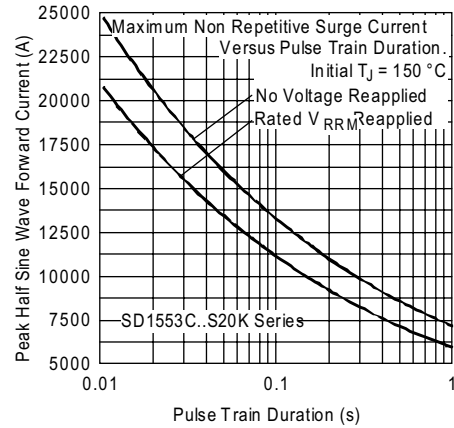


Fig. 14 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

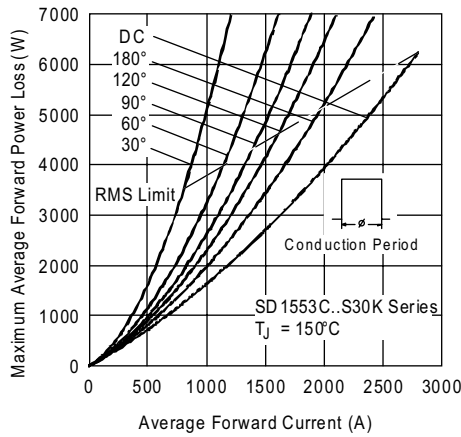


Fig. 12 - Forward Power Loss Characteristics

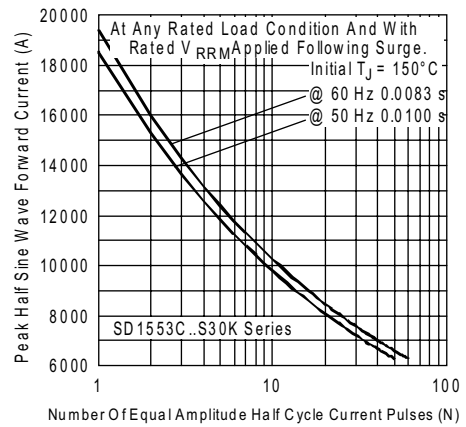


Fig. 15 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

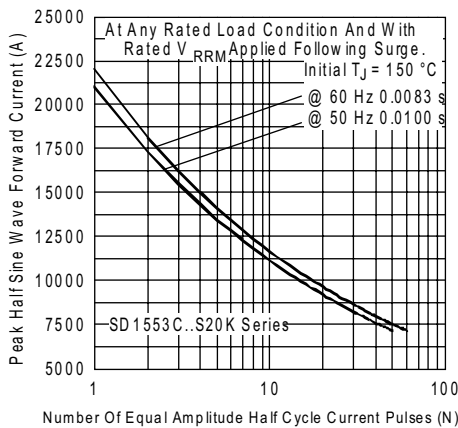


Fig. 13 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

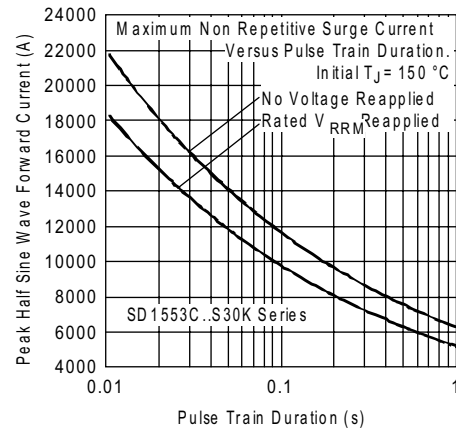


Fig. 16 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

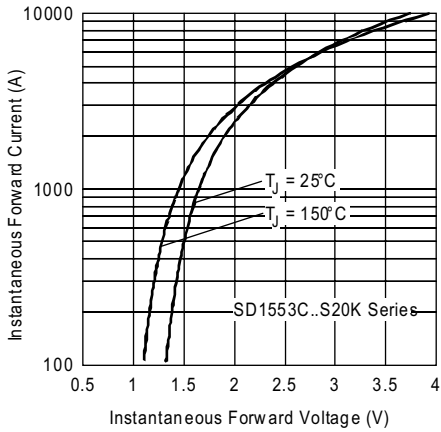


Fig. 17 - Forward Voltage Drop Characteristics

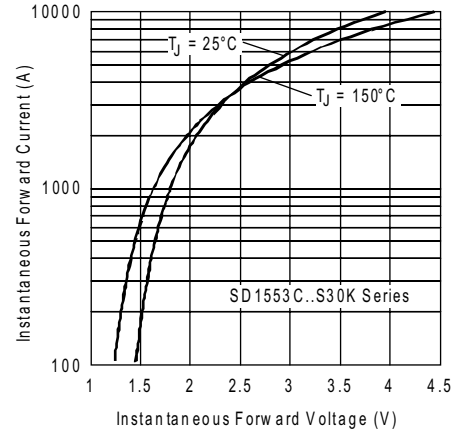


Fig. 18 - Forward Voltage Drop Characteristics

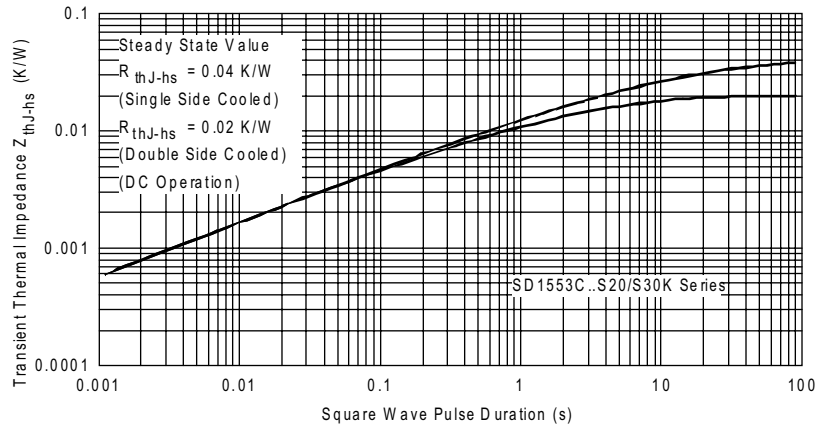


Fig. 19 - Thermal Impedance  $Z_{thJ-hs}$  Characteristic

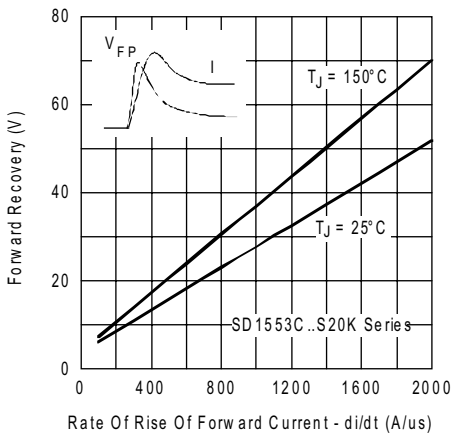


Fig. 20 - Typical Forward Recovery Characteristics

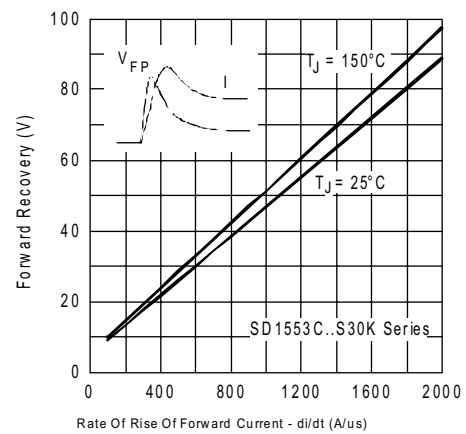


Fig. 21 - Typical Forward Recovery Characteristics

## Fast Recovery Diodes (Hockey PUK Version), 1650/1825 A

## Vishay High Power Products

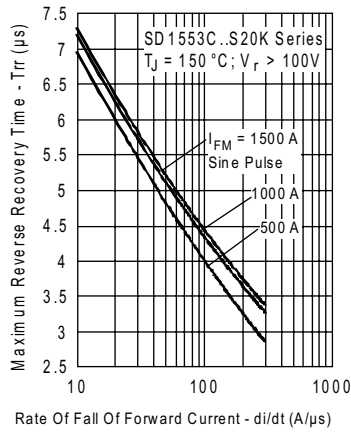


Fig. 22 - Recovery Time Characteristics

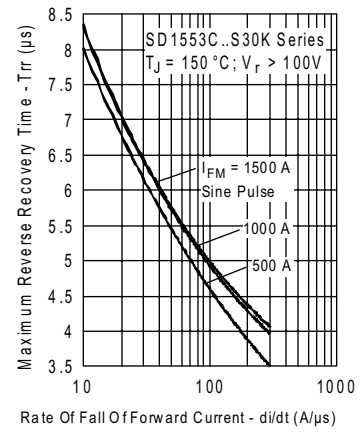


Fig. 25 - Recovery Time Characteristics

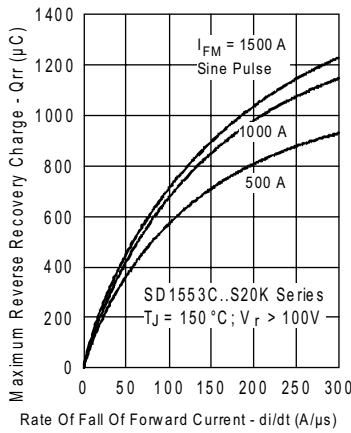


Fig. 23 - Recovery Charge Characteristics

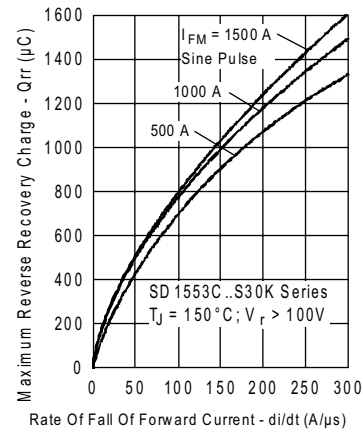


Fig. 26 - Recovery Charge Characteristics

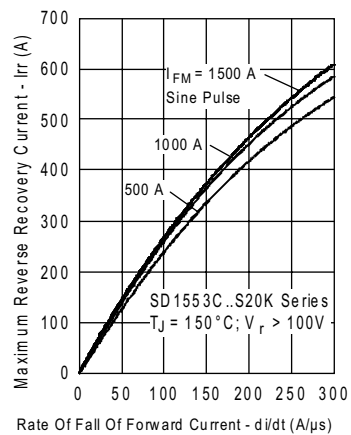


Fig. 24 - Recovery Current Characteristics

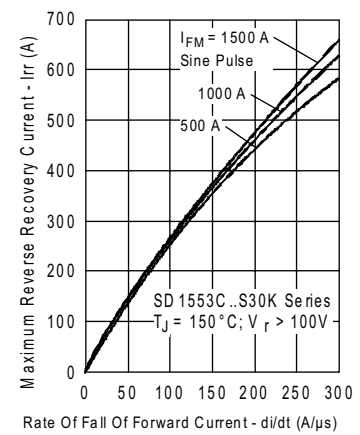


Fig. 27 - Recovery Current Characteristics

# SD1553C..K Series



Vishay High Power Products

Fast Recovery Diodes  
(Hockey PUK Version),  
1650/1825 A

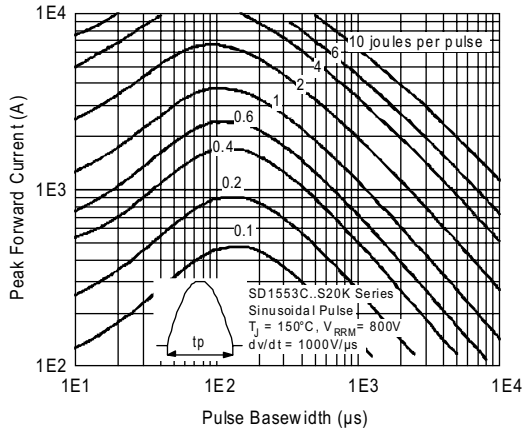


Fig. 28 - Maximum Total Energy Loss Per Pulse Characteristics

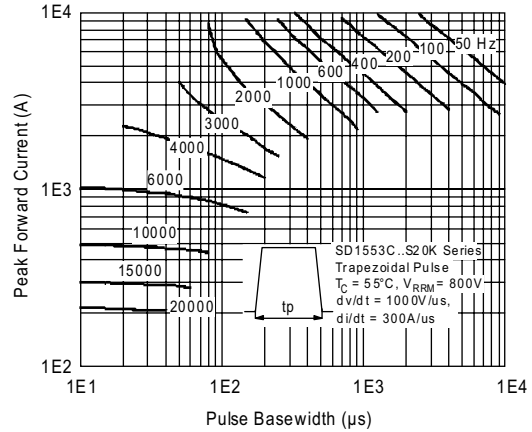


Fig. 31 - Frequency Characteristics

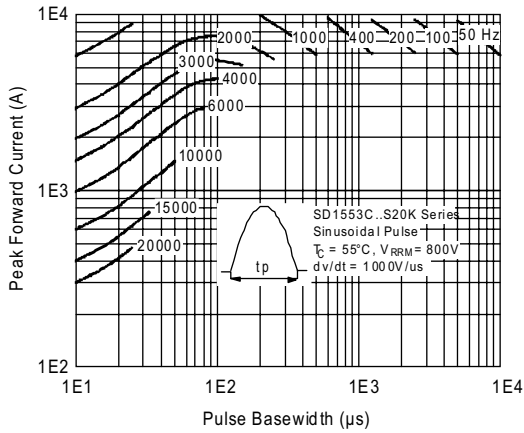


Fig. 29 - Frequency Characteristics

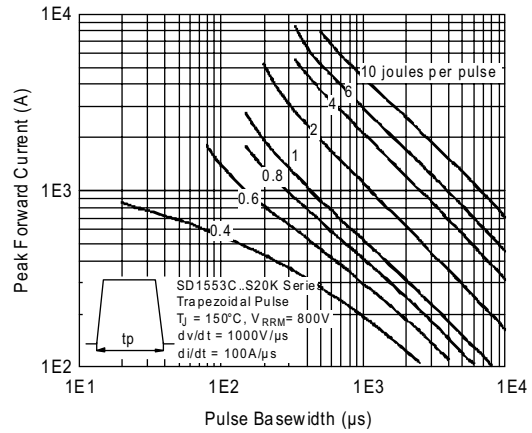


Fig. 32 - Maximum Total Energy Loss Per Pulse Characteristics

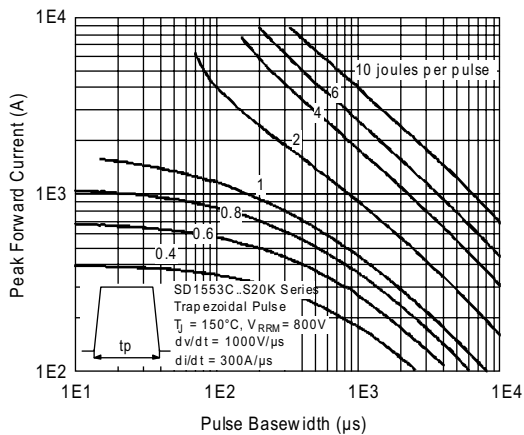


Fig. 30 - Maximum Total Energy Loss Per Pulse Characteristics

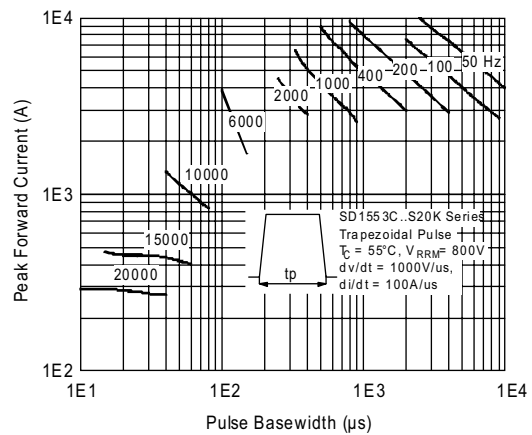


Fig. 33 - Frequency Characteristics



## Fast Recovery Diodes (Hockey PUK Version), 1650/1825 A

Vishay High Power Products

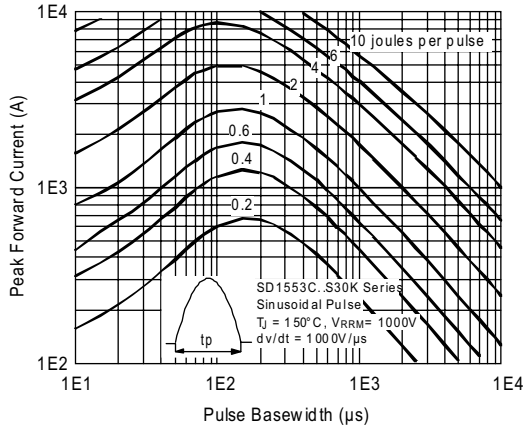


Fig. 34 - Maximum Total Energy Loss Per Pulse Characteristics

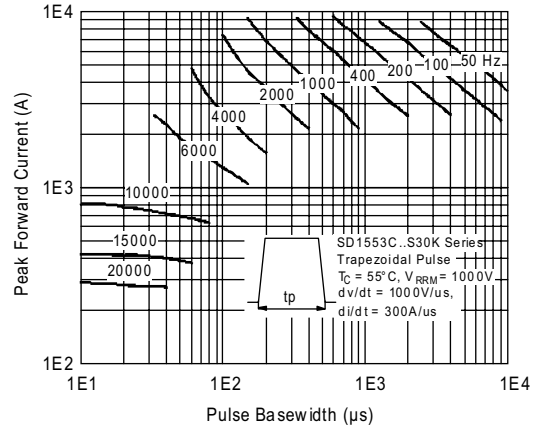


Fig. 37 - Frequency Characteristics

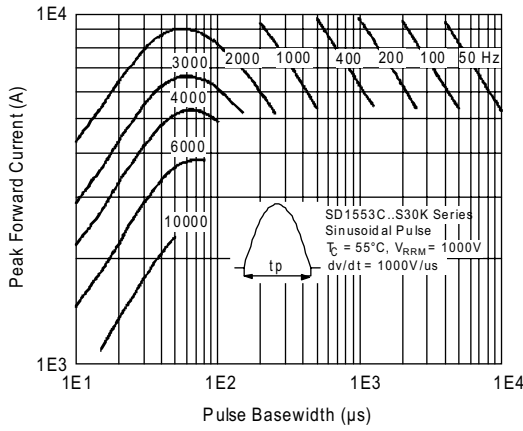


Fig. 35 - Frequency Characteristics

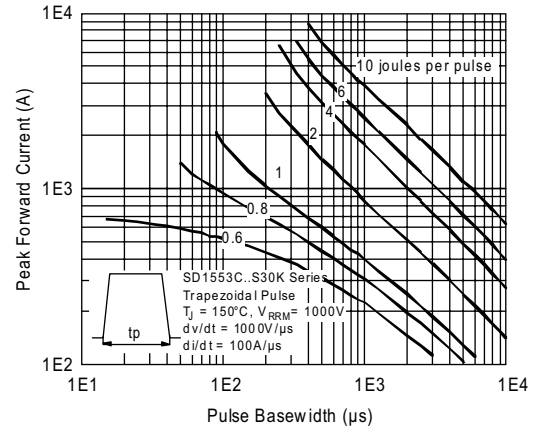


Fig. 38 - Maximum Total Energy Loss Per Pulse Characteristics

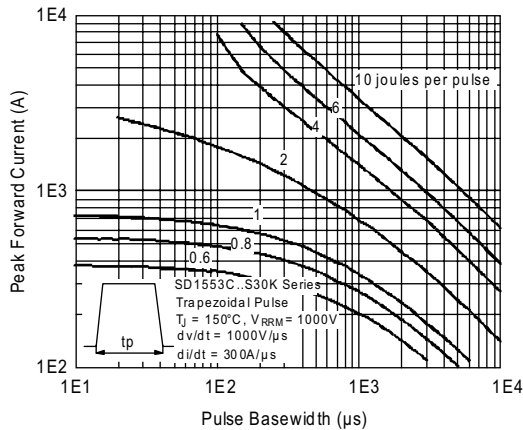


Fig. 36 - Maximum Total Energy Loss Per Pulse Characteristics

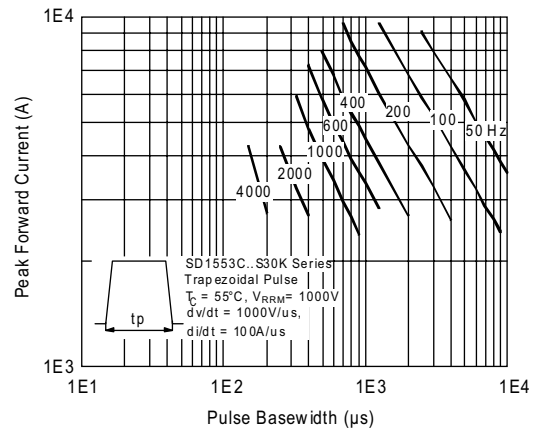


Fig. 39 - Frequency Characteristics

# SD1553C..K Series



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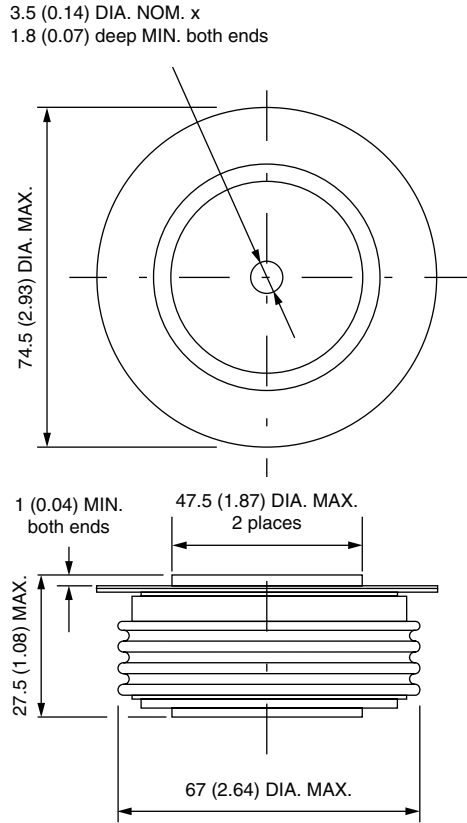
Fast Recovery Diodes  
(Hockey PUK Version),  
1650/1825 A

## ORDERING INFORMATION TABLE

Device code	<b>SD</b>	<b>155</b>	<b>3</b>	<b>C</b>	<b>30</b>	<b>S30</b>	<b>K</b>
	①	②	③	④	⑤	⑥	⑦
<b>1</b>	-	Diode					
<b>2</b>	-	Essential part number					
<b>3</b>	-	3 = Fast recovery					
<b>4</b>	-	C = Ceramic PUK					
<b>5</b>	-	Voltage code x 100 = $V_{RRM}$ (see Voltage Ratings table)					
<b>6</b>	-	$t_{rr}$ code					
<b>7</b>	-	K = PUK case DO-200AC (K-PUK)					

## DO-200AC (K-PUK)

**DIMENSIONS** in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



## Notice

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